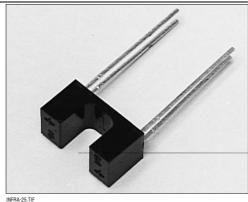
Transmissive Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- Compact package size
- · Dust protective housing
- 0.060 in.(1.52 mm)dia. detector aperture
- 0.200 in.(5.08 mm) slot width



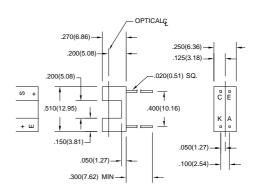
DESCRIPTION

The HOA1882 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1882-011, -012) or photodarlington (HOA1882-013) encased in a black IR transmissive thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA1882 series employs an IR transmissive housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA1882 series employs plastic molded components. For additional component information see SEP8506/8706, SDP8406, and SDP8106.

Housing material is IR transmissive polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM_053.cdr



Transmissive Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I _F =20 mA
Reverse Leakage Current	I _R			10	μΑ	V _R =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1882-011, -012 HOA1882-013	V _(BR) ceo	30 15			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector Dark Current HOA1882-011, -012 HOA1882-013	Iceo			100 250	nA	V _{CE} =10 V I _F =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1882-011 HOA1882-012 HOA1882-013	Ic(on)	0.3 1.8 4.0			mA	V _{CE} =5 V I _F =20 mA
Collector-Emitter Saturation Voltage HOA1882-011 HOA1882-012 HOA1882-013	Vce(sat)			0.4 0.4 1.1	V	I _F =20 mA I _C =40 μA I _C =230 μA I _C =500 μA
Rise And Fall Time HOA1882-011, -012 HOA1882-013	t _r , t _f		15 75		μs	Vcc=5 V, lc=1 mA R_L =1000 Ω R_L =100 Ω

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C

Storage Temperature Range -40°C to 85°C

Soldering Temperature (5 sec) 240°C

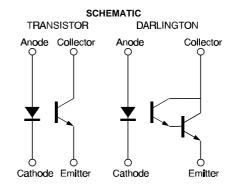
IR EMITTER

Power Dissipation 100 mW ⁽¹⁾
Reverse Voltage 3 V
Continuous Forward Current 50 mA

DETECTORTRANS.DARLINGTONCollector-Emitter Voltage30 V15 VEmitter-Collector Voltage5 V5 VPower Dissipation100 mW (¹)100 mW (¹)

Notes

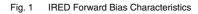
1. Derate linearly at 0.78 mW/°C above 25°C.

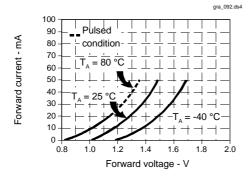


Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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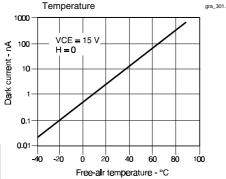
Transmissive Sensor





Non-Saturated Switching Time vs Load Resistance 1000 ▤◾▦▦ Response time - µs 100 Photodarlington = = = = Phototransistor ŦI#I# 10 100 1000 10000 Load resistance - Ohms

Fig. 3 Dark Current vs



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25

Free-air temperature - °C

50

-50

All Performance Curves Show Typical Values

75

100

Transmissive Sensor

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Honeywell:

HOA1882-011 HOA1882-012 HOA1882-013